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Contents

| | |
|------|----------------------|
| xi | Symposium Committees |
| xiii | Conference Committee |

SESSION 1 NONLINEAR AND SWITCHING DEVICES I

- 8308 04 **The Brillouin gain and experiment performance based on stimulated Brillouin scattering slow light** [8308-04]
H. Zhou, R. Zhang, K. Zhong, Beijing Univ. of Posts and Telecommunications (China)
- 8308 05 **Heterodyne method monitoring broadband slow light based on stimulated Brillouin scattering** [8308-05]
K. Zhong, H. Zhou, C. Cao, R. Zhang, Beijing Univ. of Posts and Telecommunications (China)

SESSION 2 BEST STUDENT PAPER SESSION

- 8308 07 **All-optical edge detector for NRZ signal using a SOA-MZI** [8308-07]
Q. Weng, G. Wang, X. Yang, W. Hu, Shanghai Jiao Tong Univ. (China)
- 8308 0A **Transmission characteristics of a novel grating assisted microring** [8308-10]
F. Lou, Royal Institute of Technology (Sweden); X. Zhang, Wuhan National Lab. for Optoelectronics (China) and Huazhong Univ. of Science and Technology (China); L. Wosinski, Royal Institute of Technology (Sweden) and Joint Research Ctr. of Photonics of the Royal Institute of Technology and Zhejiang Univ. (China)
- 8308 0B **Ultracompact variable optical attenuator based on photonic crystal waveguide** [8308-11]
Q. Zhao, K. Cui, Y. Huang, Tsinghua Univ. (China)
- 8308 0C **Compact surface wave polarization splitter based on the metallic-dielectric-air waveguide** [8308-12]
F. Lu, G. Li, Z. Wang, K. Li, A. Xu, Peking Univ. (China)

SESSION 3 NONLINEAR AND SWITCHING DEVICES II

- 8308 0E **All-optical 40 Gbit/s data format conversion between RZ and NRZ using a fiber delay interferometer and a single SOA** [8308-14]
F. Wang, Chongqing Univ. of Technology (China); E. Xu, Nanjing Univ. of Posts and Telecommunications (China); Y. Yu, Y. Zhang, Wuhan National Lab. for Optoelectronics (China) and Huazhong Univ. of Science and Technology (China)
- 8308 0F **Patterning effect mitigation using complementary data for NRZ wavelength conversion with a SOA-MZI** [8308-15]
G. Wang, X. Yang, Q. Weng, W. Hu, Shanghai Jiao Tong Univ. (China)

- 8308 0G **Modulation instability of optical nonlinear media: a route to chaos** [8308-17]
M. A. Sharif, Urmia Univ. of Technology (Iran, Islamic Republic of)

SESSION 4 GE AND III-V LASERS

- 8308 0J **A novel tunable semiconductor laser based on a sampled grating reflector and an interleaved sampled grating reflector** [8308-20]
H. Wang, J. Zhao, Y. Yu, Wuhan National Lab. for Optoelectronics (China)

SESSION 5 NANOSTRUCTURED MATERIALS AND QUANTUM DOTS I

- 8308 0L **Theoretical estimation of optical absorption coefficient inside an InAs/InGaAs semiconductor quantum dot** [8308-23]
S. Behjati Ardakani, H. Kaatuzian, Amirkabir Univ. of Technology (Iran, Islamic Republic of)
- 8308 0M **A 1550 nm PbS semiconductor quantum dots fiber amplifier based on SiO₂ sol-gel method** [8308-24]
X. Sun, C. Li, L. Xie, X. Liu, Y. Dong, Shanghai Univ. (China)
- 8308 0N **Control of mode Q factor and direction-emission by metal confinement for defected circular microresonators** [8308-25]
Q.-F. Yao, J.-D. Lin, Y.-D. Yang, Y.-Z. Huang, Institute of Semiconductors (China)
- 8308 0O **Transport electron through a quantum wire by side-attached asymmetric quantum-dot rings** [8308-26]
A. Rostami, Univ. of Tabriz (Iran, Islamic Republic of); S. Zabihi, H. Rasooli S., S. K. Seyyedi, Islamic Azad Univ. (Iran, Islamic Republic of)

SESSION 6 PICS

- 8308 0R **Quantifying direct DQPSK receiver with integrated photodiode array by assessing an adapted common-mode rejection ratio** [8308-29]
J. Wang, M. Lauermann, C. Zawadzki, W. Brinker, Z. Zhang, D. de Felipe, N. Keil, N. Grote, M. Schell, Fraunhofer-Institut für Nachrichtentechnik, Heinrich-Hertz-Institut (Germany)

SESSION 7 PHOTONIC CRYSTALS

- 8308 0V **K_z component dependence of photonic band gap in two-dimensional photonic crystal** [8308-33]
X. Guo, L. Han, G. Yuan, Z. Yu, Y. Liu, P. Lu, Beijing Univ. of Posts and Telecommunications (China)
- 8308 0W **Wideband slow light in one-dimensional grating waveguide** [8308-34]
C. Bao, Wuhan National Lab. for Optoelectronics (China); J. Hou, Wuhan National Lab. for Optoelectronics (China) and South-Central Univ. for Nationalities (China); H. Wu, Wuhan National Lab. for Optoelectronics (China) and Nanchang Hangkong Univ. (China); D. Gao, X. Zhang, Wuhan National Lab. for Optoelectronics (China)

SESSION 8 PLASMONICS AND SUBWAVELENGTH DEVICES

- 8308 0Y **Enhanced optical transmission through a metallic slit covered with a nanostrip and surrounded by corrugations** [8308-37]
G. Li, F. Lu, Z. Meng, A. Xu, Peking Univ. (China)
- 8308 0Z **Gain-assisted propagation of surface plasmon polaritons using electrically pumped quantum wells as active medium** [8308-38]
T. Mei, South China Normal Univ. (China); Y. Li, Nanyang Technological Univ. (Singapore); H. Zhang, N. Zhu, South China Normal Univ. (China); D. H. Zhang, Nanyang Technological Univ. (Singapore); J. Teng, A*STAR Institute of Materials Research and Engineering (Singapore)
- 8308 10 **Switchable polarization-sensitive surface plasmon resonance of highly stable gold nanorods liquid crystals composites** [8308-39]
Q. Liu, Zhejiang Univ. (China) and Univ. of Colorado at Boulder (United States); J. Qian, F. Cai, Zhejiang Univ. (China); I. I. Smalyukh, Univ. of Colorado at Boulder (United States); S. He, Zhejiang Univ. (China) and Royal Institute of Technology (Sweden)
- 8308 11 **Novel subwavelength optical signal access via a plasmonic concentrator and a dielectric microring** [8308-40]
K. Li, G. Li, Z. Wang, F. Lu, A. Xu, Peking Univ. (China)

SESSION 9 NANOSTRUCTURED MATERIALS AND QUANTUM DOTS II

- 8308 12 **Hybrid III-V/Si active microcavities based on photonic crystals (Invited Paper)** [8308-41]
P. Viktorovitch, C. Sciancalepore, Institut des Nanotechnologies de Lyon, CNRS, Univ. de Lyon (France); B. Ben Bakir, CEA-LETI Minatec (France); X. Letartre, Institut des Nanotechnologies de Lyon, CNRS, Univ. de Lyon (France); N. Olivier, CEA-LETI Minatec (France); C. Seassal, Institut des Nanotechnologies de Lyon, CNRS, Univ. de Lyon (France); D. Bordel, CEA-LETI Minatec (France); P. Rojo-Romeo, P. Regreny, Institut des Nanotechnologies de Lyon, CNRS, Univ. de Lyon (France)
- 8308 13 **Optical properties of GaN/AlN quantum dots under intense laser field** [8308-42]
L. Zhang, Z. Yu, W. Yao, Y. Liu, H. Feng, Beijing Univ. of Posts and Telecommunications (China)
- 8308 15 **A PbS quantum dot polymer optical waveguide amplifier** [8308-44]
L. Lan, F. Pang, X. Sun, T. Wang, Shanghai Univ. (China)
- 8308 16 **A dual-band UV and IR quantum cascade photodetector** [8308-45]
A. Rostami, S. Khosravi, H. Rasooli Saghai, Univ. of Tabriz (Iran, Islamic Republic of)

SESSION 10 OPTICAL INTERCONNECTS AND ACCESS DEVICES

- 8308 18 **High-speed 850 and 980 nm VCSELs for high-performance computing applications (Invited Paper)** [8308-47]
A. Mutig, P. Moser, Technische Univ. Berlin (Germany); J. A. Lott, VI Systems GmbH (Germany); P. Wolf, W. Hofmann, Technische Univ. Berlin (Germany); N. N. Ledentsov, VI Systems GmbH (Germany); D. Bimberg, Technische Univ. Berlin (Germany)

- 8308 19 **850 nm optical components for 25 Gb/s optical fiber data communication links over 100 m at 85°C** [8308-48]
S. A. Blokhin, Connector Optics LLC (Russian Federation) and A. F. Ioffe Physico-Technical Institute (Russian Federation); J. A. Lott, N. N. Ledentsov, VI Systems GmbH (Germany); L. Ya. Karachinsky, A. G. Kuzmenkov, I. I. Novikov, N. A. Maleev, Connector Optics LLC (Russian Federation) and A. F. Ioffe Physico-Technical Institute (Russian Federation); G. Fiol, D. Bimberg, Technische Univ. Berlin (Germany)

SESSION 11 NANOSTRUCTURED MATERIALS AND QUANTUM DOTS III

- 8308 1D **Quantum dot and star like lead sulfide for infrared radiation detection** [8308-52]
M. Dolatyari, S. Miri, H. Shekari, A. Bakhtiari, A. Rostami, Univ. of Tabriz (Iran, Islamic Republic of)

SESSION 12 PASSIVE INTEGRATED DEVICES

- 8308 1E **Optical routers for photonic networks-on-chip (Invited Paper)** [8308-53]
L. Yang, R. Ji, L. Zhang, Y. Tian, J. Ding, H. Chen, Y. Lu, P. Zhou, W. Zhu, Institute of Semiconductors (China)
- 8308 1F **Ultrashort and ultrabroadband silicon polarization beam splitter based on a bent directional coupler** [8308-54]
D. Dai, Univ. of California, Santa Barbara (United States) and Zhejiang Univ. (China); J. E. Bowers, Univ. of California, Santa Barbara (United States)
- 8308 1G **Novel silicon-on-insulator grating couplers based on CMOS poly-silicon gate layer** [8308-55]
C. Qiu, Shanghai Institute of Microsystem and Information Technology (China), Grace Semiconductor Manufacturing Corp. (China), and Graduate Univ. of Chinese Academy of Sciences (China); Z. Sheng, Shanghai Institute of Microsystem and Information Technology (China); L. Li, A. Pang, Grace Semiconductor Manufacturing Corp. (China); A. Wu, J. Du, J. Chen, X. Wang, F. Gan, Shanghai Institute of Microsystem and Information Technology (China); S. Zou, Shanghai Institute of Microsystem and Information Technology (China) and Grace Semiconductor Manufacturing Corp. (China)
- 8308 1H **An analysis of electro-optic measurement of electric fields using Jones matrix formulation** [8308-56]
H. Ismail, A. Nirmalathas, E. Skafidas, The Univ. of Melbourne (Australia)
- 8308 1I **Investigation of the use of rotating linearly polarized light for characterizing SiO₂ thin film on Si substrate** [8308-57]
C. Pawong, R. Chitaree, C. Soankwan, Mahidol Univ. (Thailand)

SESSION 13 SILICON PHOTONICS I

- 8308 1K **1x3 optical drop splitter in a rod-type silicon photonic crystal** [8308-59]
D. Zhuang, Fujian Normal Univ. (China); X. Chen, Minjiang Univ. (China); J. Li, Fujian Normal Univ. (China); G. Lin, Minjiang Univ. (China); Z. Qiang, Y. Qiu, H. Li, Fujian Normal Univ. (China)

- 8308 1L **CMOS-compatible thermal compensator based on a modified Mach-Zender interferometer** [8308-60]
Q. Long, H. Yi, X. Wang, Peking Univ. (China); Z. Zhou, Peking Univ. (China) and Georgia Institute of Technology (United States)

SESSION 14 SILICON PHOTONICS II

- 8308 1M **High-speed silicon optical modulators (Invited Paper)** [8308-61]
G. T. Reed, D. Thomson, F. Y. Gardes, N. G. Emerson, Univ. of Surrey (United Kingdom); J.-M. Fédéli, CEA-LETI Minatec (France)

SESSION 15 TELECOM POST-DEADLINE PAPERS: JOINT SESSION WITH CONFERENCES 8307, 8309, AND 8310

- 8308 1P **Low-voltage, high-extinction ratio carrier-depletion Mach-Zehnder silicon optical modulator** [8308-89]
J. Ding, H. Chen, R. Ji, L. Yang, Y. Tian, L. Zhang, W. Zhu, Y. Lu, R. Min, P. Zhou, Institute of Semiconductors (China)

SESSION 16 POST-DEADLINE PAPERS: JOINT SESSION WITH CONFERENCE 8311

- 8308 1R **Broad gain injectorless quantum-cascade lasers with low threshold emitting around 8.6 μm** [8308-91]
H. Li, S. Katz, G. Boehm, M.-C. Amann, Walter Schottky Institut (Germany)

POSTER SESSION

- 8308 1S **Optical logic operation for AND gate based on planar photonic crystal circuit** [8308-16]
K.-Y. Lee, China Univ. of Science and Technology (Taiwan, China); Y.-P. Yang, I.-C. Yang, National Central Univ. (Taiwan, China); Y.-L. Tsai, H.-F. Liao, Y.-J. Lin, W.-Y. Lee, China Univ. of Science and Technology; Y.-T. Tsai, National Central Univ. (Taiwan, China)
- 8308 1T **Three-wavelength multiplexer/demultiplexer based on photonic crystal ring resonator and cavities** [8308-35]
J. Zhang, X.-M. Xu, L.-J. He, Nanchang Univ. (China)
- 8308 1U **Highly efficient channel drop filter based on photonic crystal one-way waveguide** [8308-64]
H. Ren, H. Wen, Y. Qin, S. Guo, Zhejiang Univ. of Technology (China); W. Hu, C. Jiang, Y. Jin, Shanghai Jiao Tong Univ. (China)
- 8308 1V **Intracavity frequency doubling of PPKTP-based optical parametric oscillator** [8308-65]
Q. Li, J. Tian, Beijing Univ. of Technology (China); X. Zhang, Y. Song, L. Wang, Beijing Univ. of Technology (United States)
- 8308 1W **Dual-depletion-region lumped electroabsorption modulator for low capacitance and expected high bandwidth** [8308-66]
Y. Shao, L. Zhao, H. Yu, J. Pan, B. Wang, H. Zhu, W. Wang, Institute of Semiconductors (China)

- 8308 1X **Polyatomic photonic crystal waveguides with semi-slow light and tailored dispersion properties** [8308-69]
D. Wang, Lanzhou Univ. of Technology (China) and Beijing Univ. of Posts and Telecommunications (China); J. Zhang, Beijing Univ. of Posts and Telecommunications (China); L. Yuan, J. Lei, Lanzhou Univ. of Technology (China); S. Chen, J. Han, Y. Zhao, Beijing Univ. of Posts and Telecommunications (China)
- 8308 1Y **Microscopic study on the carrier distribution in optoelectronic device structures: experiment and modeling** [8308-70]
W. Huang, H. Xia, S. Wang, H. Deng, P. Wei, Shanghai Institute of Technical Physics (China); L. Li, F. Liu, Institute of Semiconductors (China); Z. Li, T. Li, Shanghai Institute of Technical Physics (China)
- 8308 1Z **Modeling of white light emitting diodes (WLED) based on GaN/InGaN multi quantum dots structure** [8308-71]
A. Rostami, B. Rostami Dogolsara, H. Rasooli Saghai, M. Leilaeioun, Univ. of Tabriz (Iran, Islamic Republic of)
- 8308 20 **Zinc oxide nanoplates for ultraviolet radiation detection** [8308-72]
M. Dolatyari, E. Amini, H. Shekari, A. Bakhtiari, A. Rostami, Univ. of Tabriz (Iran, Islamic Republic of)
- 8308 21 **Ultrahigh-speed all-optical wavelength conversion for PoISK signal based on parallel dual-pump FWM in SOA** [8308-73]
P. Li, W. Shi, Nanjing Univ. of Posts and Telecommunications (China); D. Huang, Wuhan National Lab. for Optoelectronics (China)
- 8308 22 **Multiwavelength converter exploiting cross-gain modulation in SFRL** [8308-74]
T. Pan, P. Li, S. Huang, Z. Zhao, Nanjing Univ. of Posts and Telecommunications (China)
- 8308 24 **Hybrid-integrated coherent receiver using silica-based planar lightwave circuit technology** [8308-76]
J.-H. Kim, J.-S. Choe, K.-S. Choi, C.-J. Youn, D.-J Kim, S.-H. Jang, Y.-H. Kwon, E.-S. Nam, Electronics and Telecommunications Research Institute (Korea, Republic of)
- 8308 26 **Preparation of gold colloid and its surface-enhanced Raman scattering properties** [8308-78]
L. Hu, Z. Chen, N. Chen, W. Zhang, H. Zhu, S. Liu, T. Wang, Shanghai Univ. (China)
- 8308 27 **Multichannel analog-to-digital converters based on current mirrors for the optical systems** [8308-79]
V. G. Krasilenko, Open International Univ. of Human Development (Ukraine); A. I. Nikolskyy, M. A. Nikolska, Vinnitsa National Technical Univ. (Ukraine); R. F. Lobodzinska, Open International Univ. of Human Development (Ukraine)
- 8308 29 **Experimental research on 10 Gb/s all-optical logic gates with return-to-zero data in high nonlinear fiber** [8308-81]
W. Wang, J. Yu, Tianjin Univ. (China); B. Han, Tianjin Univ. (China) and Shanxi Datong Univ. (China); J. Guo, J. Luo, J. Wang, Y. Liu, E. Yang, Tianjin Univ. (China)

- 8308 2A **40GHz optoelectronic oscillator with low-frequency optical and microwave devices** [8308-82]
 B. Han, Tianjin Univ. (China) and Shanxi Datong Univ. (China); J. Yu, W. Wang, J. Guo, J. Wang, E. Yang, Tianjin Univ. (China)
- 8308 2B **The effect of growth temperature on InAs quantum dots grown by MOCVD** [8308-83]
 T. Li, X. Guo, Q. Wang, P. Wang, Z. Jia, X. Ren, Y. Huang, S. Cai, Beijing Univ. of Posts and Telecommunications (China)
- 8308 2C **Effect of boron on the surface and optical properties for (B)InAs/GaAs self-assembled quantum dots grown by MOCVD** [8308-84]
 P. Wang, Q. Wang, X. Guo, Z. Jia, T. Li, X. Ren, S. Cai, Beijing Univ. of Posts and Telecommunications (China)
- 8308 2D **Analysis and optimization of a dual-absorption RCE photodetector for high-speed applications** [8308-85]
 D. Li, Y. Huang, X. Duan, W. Wang, X. Ren, Beijing Univ. of Posts and Telecommunications (China)
- 8308 2E **Design and analysis of resonant cavity enhanced photodetector by using InP-based concentric circular subwavelength grating** [8308-86]
 T. Wang, Y. Huang, X. Duan, Y. Shang, W. Wang, X. Ren, Beijing Univ. of Posts and Telecommunications (China)
- 8308 2F **Study of the dynamics of the nonlinear polarization rotation in a semiconductor optical amplifier** [8308-87]
 O. Pérez-Cortés, Ctr. de Investigación Científica y de Educación Superior de Ensenada (Mexico); A. Albores-Mejía, Eindhoven Univ. of Technology (Netherlands); H. Soto-Ortiz, Ctr. de Investigación Científica y de Educación Superior de Ensenada (Mexico)
- 8308 2G **Analysis of SHB and thermal characteristics in PC-VCSEL considering photonic crystal parameters** [8308-88]
 G. Haghigiat, V. Ahmadi, S. Pahlavan, Tarbiat Modares Univ. (Iran, Islamic Republic of)

Author Index

Symposium Committees

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